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Kind regards,

Team Nexperia

40 V, 200 mA PNP switching transistor
Rev. 1 — 2 April 2012

Product data sheet

Product profile

1.1 General description

PNP single switching transistor in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package.

NPN complement: PMBT3904MB.

1.2 Features and benefits

- Single general-purpose switching transistor
- AEC-Q101 qualified
- Ultra small SMD plastic package
- Board-space reduction
- Low package height of 0.37 mm

1.3 Applications

- General-purpose switching and amplification
- Mobile applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-40	V
I_{C}	collector current		-	-	-200	mA
h _{FE}	DC current gain	$V_{CE} = -1 \text{ V};$ $I_{C} = -10 \text{ mA}$	100	180	300	

2. Pinning information

Table 2. **Pinning**

	3		
Pin	Description	Simplified outline	Graphic symbol
1	base		
2	emitter	1 3	3
3	collector	2 🔲	1—
		Transparent	. ,
		top view	2
			sym013



3. Ordering information

Table 3. Ordering information

Type number			
	Name	Description	Version
PMBT3906MB	DFN1006B-3	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.37$ mm	SOT883B

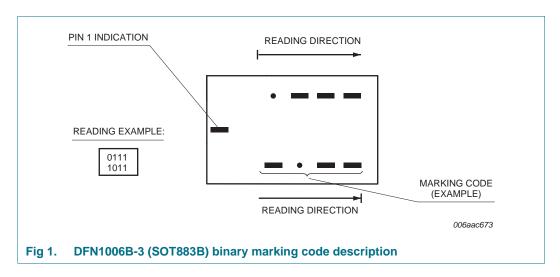
4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PMBT3906MB	0100 1000

[1] For DFN1006B-3 (SOT883B) binary marking code description, see Figure 1.

4.1 Binary marking code description



5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		•	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-40	V
V_{CEO}	collector-emitter voltage	open base	-	-40	V
V_{EBO}	emitter-base voltage	open collector	-	-6	V
I _C	collector current		-	-200	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-200	mA
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[1][2] _	250	mW
			[1][3]	590	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Reflow soldering is the only recommended soldering method.

^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

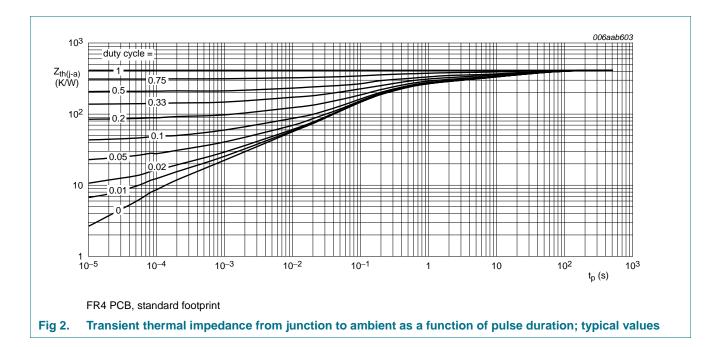
^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1][2]	-	500	K/W
	junction to ambient		[1][3]	-	212	K/W

- [1] Reflow soldering is the only recommended soldering method.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².



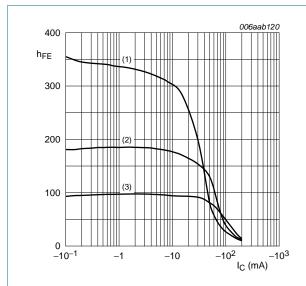
7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$	-	-	-50	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -6 \text{ V}; I_{C} = 0 \text{ A}$	-	-	-50	nA
h _{FE}	DC current gain	$V_{CE} = -1 V$				
		$I_{C} = -0.1 \text{ mA}$	60	180	-	
		$I_C = -1 \text{ mA}$	80	180	-	
		$I_C = -10 \text{ mA}$	100	180	300	
		$I_C = -50 \text{ mA}$	60	130	-	
		$I_C = -100 \text{ mA}$	[1] 30	50	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$	-	-100	-250	mV
		$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	-	-165	-400	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$	-	-750	-850	mV
		$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	-	-850	-950	mV
t _d	delay time	$V_{CC} = -3 \text{ V};$ $I_{C} = -10 \text{ mA};$	-	-	35	ns
t _r	rise time		-	-	35	ns
t _{on}	turn-on time	- I _{Bon} = -1 mA; - I _{Boff} = 1 mA	-	-	70	ns
t _s	storage time	5011	-	-	225	ns
t _f	fall time		-	-	75	ns
t _{off}	turn-off time		-	-	300	ns
C _c	collector capacitance	$V_{CB} = -5 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	4.5	pF
C _e	emitter capacitance	$V_{EB} = -500 \text{ mV};$ $I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$	-	-	10	pF
f _T	transition frequency	$V_{CE} = -20 \text{ V};$ $I_{C} = -10 \text{ mA};$ f = 100 MHz	250	-	-	MHz
NF	noise figure	$V_{CE} = -5 \text{ V};$ $I_{C} = -100 \text{ μA}; R_{S} = 1 \text{ k}\Omega;$ $f = 10 \text{ Hz to } 15.7 \text{ kHz}$	-	-	4	dB

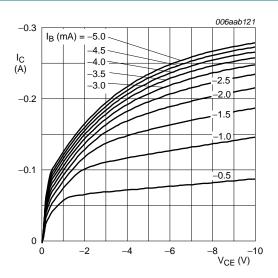
^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$



$$V_{CE} = -1 V$$

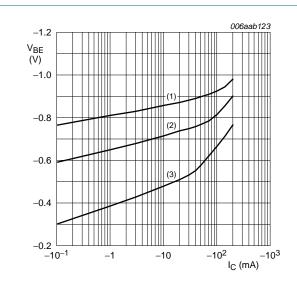
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 3. DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Fig 4. Collector current as a function of collector-emitter voltage; typical values



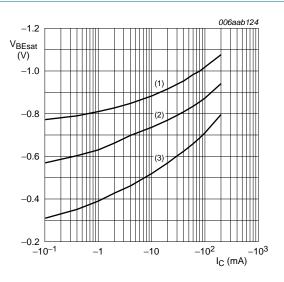
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 5. Base-emitter voltage as a function of collector current; typical values



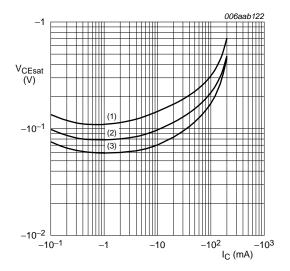
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 6. Base-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B}=10$$

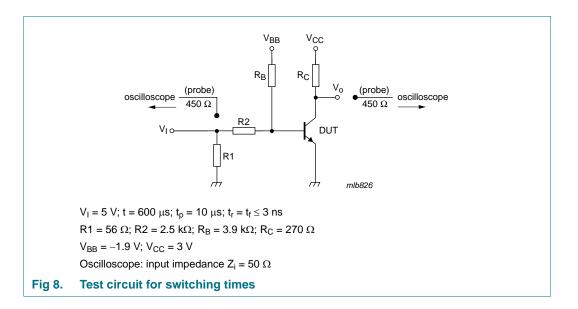
(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values

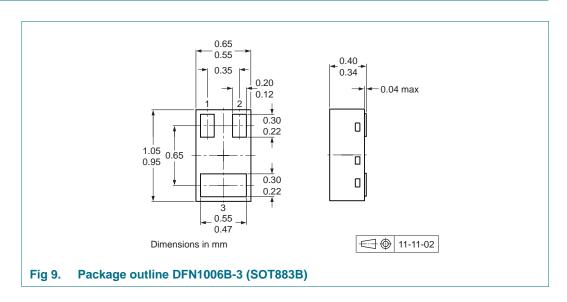
8. Test information



Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

10. Package outline



11. Packing information

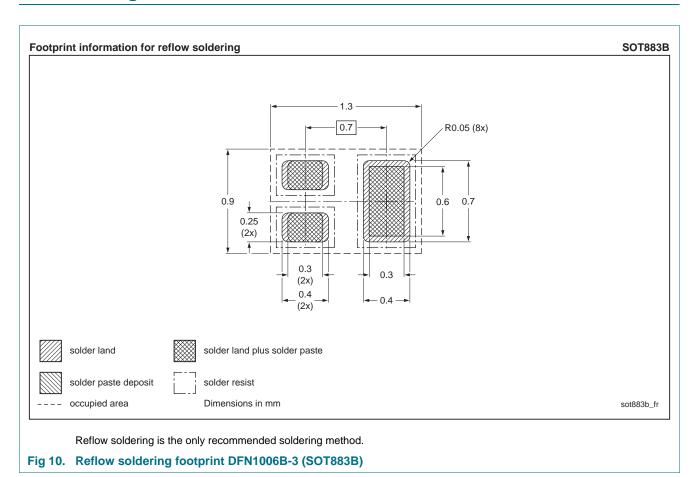
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity 10000
PMBT3906MB	DFN1006B-3 (SOT883B)	2 mm pitch, 8 mm tape and reel	-315

^[1] For further information and the availability of packing methods, see Section 15.

12. Soldering



40 V, 200 mA PNP switching transistor

13. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMBT3906MB v.1	20120402	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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40 V, 200 mA PNP switching transistor

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40 V, 200 mA PNP switching transistor

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